

#### The RF MOSFET Line 100W, 500MHz, 28V

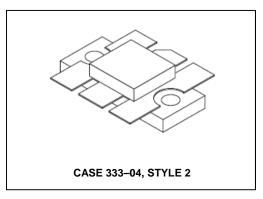
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Designed for broadband commercial and military applications using single ended circuits at frequencies to 500 MHz. The high power, high gain and broadband performance of this device makes possible solid state transmitters for FM broadcast or TV channel frequency bands.

#### N-Channel enhancement mode

- Guaranteed performance @ 500 MHz, 28 Vdc Output power — 100 W Power gain — 8.8 dB typ. Efficiency — 55% typ.
- 100% ruggedness tested at rated output power
- Low thermal resistance
- Low Crss 17 pF typ. @ VDS = 28 V

#### **Product Image**



#### MAXIMUM RATINGS

| Rating   | Symbol           | Value       | Unit          |
|--|------------------|-------------|---------------|
| Drain-Source Voltage   | V <sub>DSS</sub> | 65          | Vdc           |
| Gate-Source Voltage  | VGS              | ±20         | Vdc           |
| Drain Current — Continuous   | ID               | 13          | Adc           |
| Total Device Dissipation @ T <sub>C</sub> = 25°C Derate above 25°C | PD               | 270<br>1.54 | Watts<br>W/°C |
| Storage Temperature Range  | T <sub>stg</sub> | -65 to +150 | °C            |
| Operating Junction Temperature                                     | TJ               | 200         | °C            |

#### THERMAL CHARACTERISTICS

| Characteristic                       | Symbol           | Max  | Unit |
|--------------------------------------|------------------|------|------|
| Thermal Resistance, Junction to Case | R <sub>eJC</sub> | 0.65 | °C/W |

#### ELECTRICAL CHARACTERISTICS (TC = 25°C unless otherwise noted)

| Characteristic   | Symbol   | Min | Тур | Max | Unit |
|--|----------|-----|-----|-----|------|
| OFF CHARACTERISTICS  |          |     |     |     |      |
| Drain–Source Breakdown Voltage<br>(V <sub>GS</sub> = 0, I <sub>D</sub> = 50 mA)  | V(BR)DSS | 65  | _   | _   | Vdc  |
| Zero Gate Voltage Drain Current<br>(V <sub>DS</sub> = 28 V, V <sub>GS</sub> = 0) | IDSS     | _   | _   | 2.5 | mAdc |
| Gate-Body Leakage Current<br>(VGS = 20 V, VDS = 0)                               | IGSS     | _   | _   | 1.0 | μAdc |

NOTE - CAUTION - MOS devices are susceptible to damage from electrostatic charge. Reasonable precautions in handling and packaging MOS devices should be observed.

typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available.

Commitment to produce in volume is not guaranteed.



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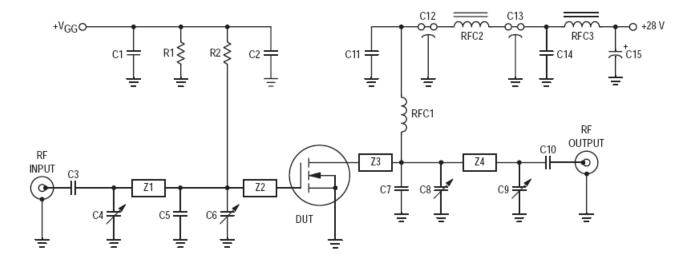
#### ELECTRICAL CHARACTERISTICS — continued (T<sub>C</sub> = 25°C unless otherwise noted)

| Characteristic   | Symbol              | Min | Тур         | Max           | Unit |
|--|---------------------|-----|-------------|---------------|------|
| ON CHARACTERISTICS   |                     |     |             |               |      |
| Gate Threshold Voltage (V <sub>DS</sub> = 10 V, I <sub>D</sub> = 100 mA)   | V <sub>GS(th)</sub> | 1.5 | 2.5         | 4.5           | Vdc  |
| Drain-Source On-Voltage (VGS = 10 V, ID = 5.0 A)   | VDS(on)             | 0.5 | 0.9         | 1.5           | Vdc  |
| Forward Transconductance (V <sub>DS</sub> = 10 V, I <sub>D</sub> = 2.5 A)  | 9fs                 | 3.0 | 3.75        | _             | mhos |
| DYNAMIC CHARACTERISTICS  |                     |     |             |               |      |
| Input Capacitance (VDS = 28 V, VGS = 0, f = 1.0 MHz)   | Ciss                | _   | 135         | _             | pF   |
| Output Capacitance (V <sub>DS</sub> = 28 V, V <sub>GS</sub> = 0, f = 1.0 MHz)  | Coss                | _   | 140         | _             | pF   |
| Reverse Transfer Capacitance ( $V_{DS}$ = 28 V, $V_{GS}$ = 0, f = 1.0 MHz)   | C <sub>rss</sub>    | _   | 17          | _             | pF   |
| FUNCTIONAL CHARACTERISTICS   |                     |     |             |               |      |
| Common Source Power Gain<br>(V <sub>DD</sub> = 28 Vdc, P <sub>out</sub> = 100 W, f = 500 MHz, I <sub>DQ</sub> = 100 mA)                                | G <sub>ps</sub>     | 7.5 | 8.8         | _             | dB   |
| Drain Efficiency<br>(V <sub>DD</sub> = 28 Vdc, P <sub>out</sub> = 100 W, f = 500 MHz, I <sub>DQ</sub> = 100 mA)  | η                   | 50  | 55          | _             | %    |
| Electrical Ruggedness<br>(V <sub>DD</sub> = 28 Vdc, P <sub>out</sub> = 100 W, f = 500 MHz, I <sub>DQ</sub> = 100 mA,<br>VSWR 10:1 at all Phase Angles) | Ψ                   | No  | Degradation | in Output Pov | ver  |

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C1, C11, C14 C2 C3, C10 C4, C6, C8, C9 C5 C7 C12, C13 C15

0.1 μF, Ceramic Capacitor 240 pF, ATC Type Chip Capacitor 270 pF, ATC Type Chip Capacitor 1-20 pF, Trimmer Capacitor, Johansen 24 pF, Mini-Unelco Type Capacitor 24 pF, Mini-Unelco Type Capacitor 680 pF, Feedthru Capacitors 10 μF, 50 V, Electrolytic Capacitor

RFC1 RFC2, RFC3 Z1, Z2, Z3 Z4

Board Material

8 Turns AWG #18, 0.25" I.D., Enameled Ferroxcube VK200 19/4B 0.250" x 0.800", Microstrip Line 0.250" x 0.400", Microstrip Line 0.250" x 1.25", Microstrip Line 0.062" Glass Teflon®, 2 oz. Copper, Double Clad Copper Board,  $\varepsilon_r = 2.55$ 

Figure 1. 500 MHz Test Circuit

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#### TYPICAL CHARACTERISTICS

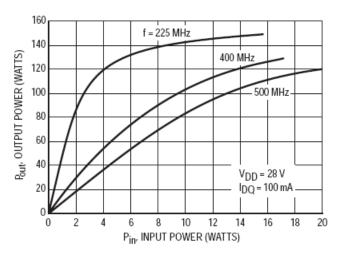


Figure 2. Output Power versus Input Power

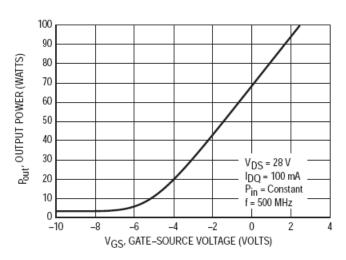


Figure 3. Output Power versus Gate Voltage

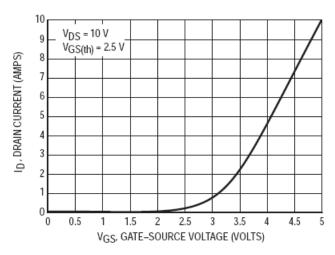


Figure 4. Drain Current versus Gate Voltage (Transfer Characteristics)

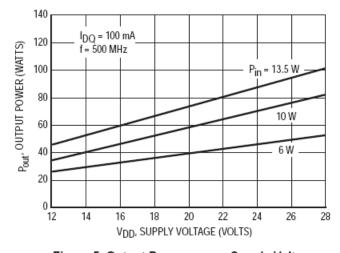


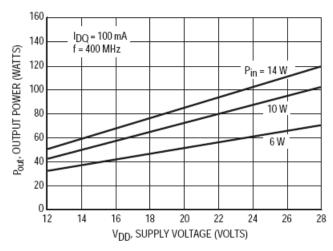
Figure 5. Output Power versus Supply Voltage

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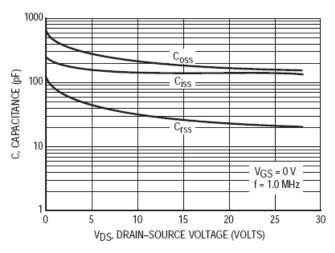


160  $I_{DQ} = 100 \text{ mA}$ 140  $P_{in} = 8 \text{ W}$ Pout, OUTPUT POWER (WATTS) f = 225 MHz 120 ΔW 100 80 2 W 20 24 12 14 20 22 26 28 VDD, SUPPLY VOLTAGE (VOLTS)

Figure 6. Output Power versus Supply Voltage

Figure 7. Output Power versus Supply Voltage

#### TYPICAL CHARACTERISTICS





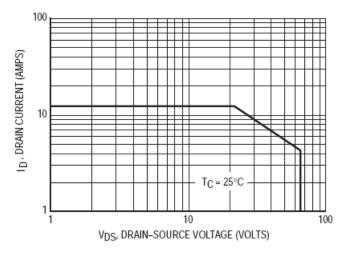
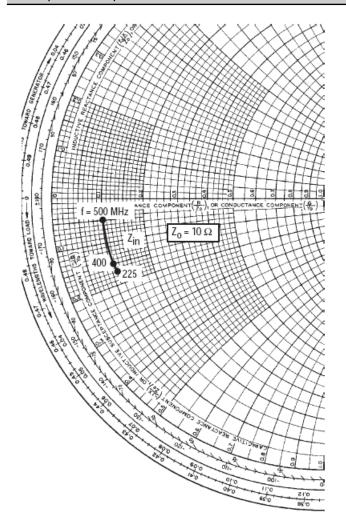
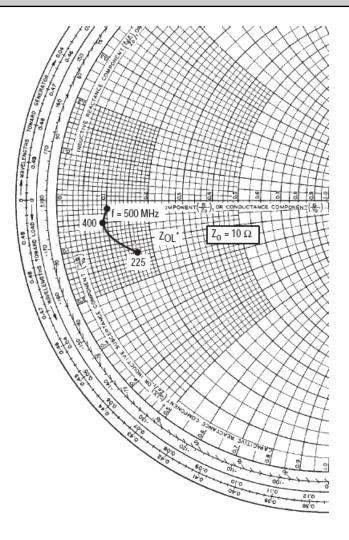


Figure 9. DC Safe Operating Area

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VDD = 28 V, IDO = 100 mA, Pout = 100 W

| - |            | our                     |
|---|------------|-------------------------|
|   | f<br>(MHz) | Z <sub>in</sub><br>Ohms |
|   | 225        | 1.1 – j1.7              |
|   | 400        | 1.08 – j1.5             |
|   | 500        | 1.0 – j0.5              |

 $V_{DD} = 28 \text{ V}, I_{DQ} = 100 \text{ mA}, P_{out} = 100 \text{ W}$ 

| f<br>(MHz) | Z <sub>OL</sub> *<br>Ohms |
|------------|---------------------------|
| 225        | 1.6 – j1.3                |
| 400        | 0.9 – j0.5                |
| 500        | 1.0 – j0.2                |

Z<sub>OL</sub>\* = Conjugate of the optimum load impedance into which the device operates at a given output power, voltage and frequency.

Figure 10. Series Equivalent Input/Output Impedance

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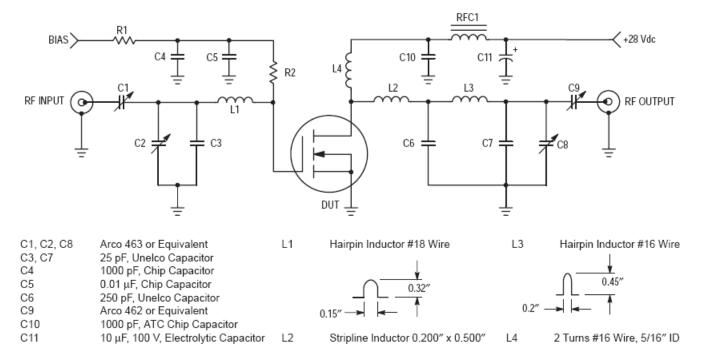


Figure 11. 225 MHz Test Circuit

RFC1

R1

R2

VK200-4B

1.0 k, 1/4 W Resistor

100 Ω Resistor

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C13



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Board Material 0.062" Teflon®,

Fiberglass, 1 oz. Copper,

Clad Both Sides,  $\varepsilon_r = 2.56$ 

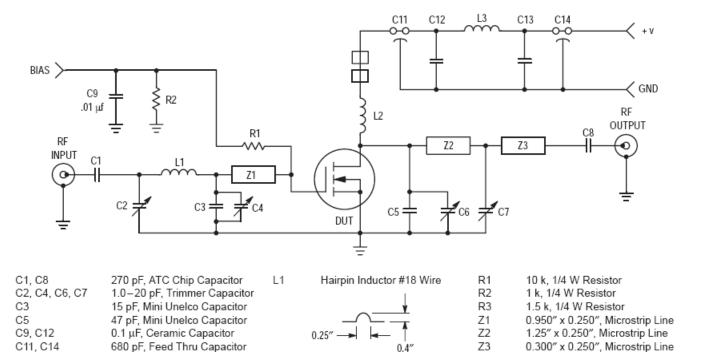


Figure 12. 400 MHz Test Circuit

12 Turns #18 Wire, 0.450" ID

Ferroxcube VK200 20/4B

L2

L3

50 μF, Tantalum Capacitor

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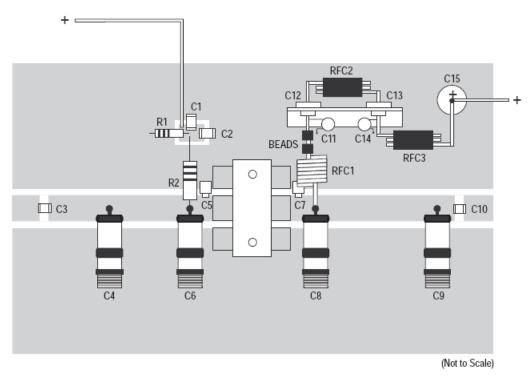


Figure 13. MRF275L Component Location (500 MHz)

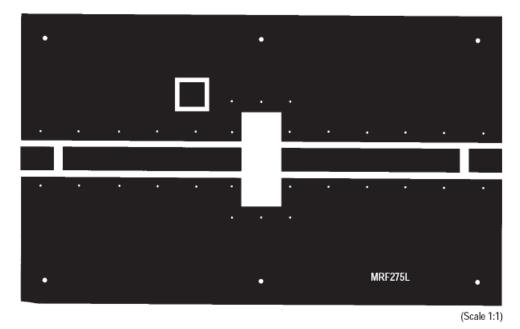


Figure 14. MRF275L Test Circuit Photomaster (Reduced 18% in printed data book, DL110/D)

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Table 1. Common Source S-Parameters (VDS = 12.5 V, ID = 4.5 A)

| f   |                 | 11   | non Source s     | 21 |                 | 12 | \$ <sub>22</sub> |      |  |
|-----|-----------------|------|------------------|----|-----------------|----|------------------|------|--|
| MHz | S <sub>11</sub> | ф    | \$ <sub>21</sub> | ф  | S <sub>12</sub> | ф  | S <sub>22</sub>  | ф    |  |
| 30  | 0.936           | -176 | 6.22             | 87 | 0.010           | 21 | 0.944            | -179 |  |
| 40  | 0.938           | -178 | 4.28             | 87 | 0.010           | 24 | 0.930            | -177 |  |
| 50  | 0.937           | -178 | 3.65             | 83 | 0.010           | 29 | 0.922            | 179  |  |
| 60  | 0.937           | -179 | 2.99             | 83 | 0.011           | 34 | 0.920            | 179  |  |
| 70  | 0.938           | -179 | 2.54             | 81 | 0.011           | 39 | 0.917            | 179  |  |
| 80  | 0.938           | -179 | 2.18             | 80 | 0.012           | 42 | 0.913            | 179  |  |
| 90  | 0.939           | -180 | 1.94             | 78 | 0.012           | 44 | 0.909            | 180  |  |
| 100 | 0.939           | -180 | 1.77             | 77 | 0.013           | 47 | 0.913            | -180 |  |
| 110 | 0.939           | 180  | 1.57             | 77 | 0.015           | 50 | 0.916            | -179 |  |
| 120 | 0.940           | 180  | 1.45             | 74 | 0.015           | 54 | 0.914            | 179  |  |
| 130 | 0.940           | 179  | 1.34             | 75 | 0.016           | 57 | 0.935            | 180  |  |
| 140 | 0.940           | 179  | 1.26             | 72 | 0.016           | 58 | 0.943            | 180  |  |
| 150 | 0.940           | 179  | 1.19             | 71 | 0.017           | 57 | 0.951            | 178  |  |
| 160 | 0.941           | 179  | 1.09             | 70 | 0.019           | 58 | 0.943            | 179  |  |
| 170 | 0.941           | 179  | 1.01             | 69 | 0.019           | 62 | 0.940            | 180  |  |
| 180 | 0.941           | 179  | 0.956            | 68 | 0.021           | 64 | 0.948            | 179  |  |
| 190 | 0.941           | 178  | 0.912            | 67 | 0.022           | 65 | 0.957            | 180  |  |
| 200 | 0.942           | 178  | 0.860            | 65 | 0.022           | 65 | 0.941            | 178  |  |
| 210 | 0.942           | 178  | 0.816            | 64 | 0.023           | 65 | 0.931            | 178  |  |
| 220 | 0.943           | 178  | 0.779            | 63 | 0.025           | 66 | 0.922            | 178  |  |
| 230 | 0.943           | 177  | 0.717            | 60 | 0.027           | 67 | 0.965            | 177  |  |
| 240 | 0.943           | 177  | 0.709            | 61 | 0.026           | 68 | 0.927            | 176  |  |
| 250 | 0.944           | 177  | 0.674            | 60 | 0.026           | 70 | 0.924            | 178  |  |
| 260 | 0.944           | 177  | 0.645            | 58 | 0.028           | 69 | 0.930            | 179  |  |
| 270 | 0.944           | 177  | 0.627            | 57 | 0.030           | 70 | 0.933            | 178  |  |
| 280 | 0.945           | 176  | 0.608            | 58 | 0.032           | 70 | 0.940            | 177  |  |
| 290 | 0.946           | 176  | 0.580            | 54 | 0.031           | 71 | 0.941            | 175  |  |
| 300 | 0.946           | 176  | 0.569            | 56 | 0.033           | 71 | 0.945            | 176  |  |
| 310 | 0.946           | 176  | 0.539            | 55 | 0.033           | 72 | 0.953            | 178  |  |
| 320 | 0.947           | 175  | 0.512            | 54 | 0.035           | 71 | 0.952            | 177  |  |
| 330 | 0.948           | 175  | 0.483            | 51 | 0.037           | 72 | 0.927            | 176  |  |
| 340 | 0.947           | 175  | 0.477            | 52 | 0.038           | 72 | 0.921            | 176  |  |
| 350 | 0.947           | 175  | 0.466            | 51 | 0.039           | 75 | 0.929            | 178  |  |
| 360 | 0.947           | 175  | 0.459            | 51 | 0.040           | 73 | 0.963            | 177  |  |
| 370 | 0.948           | 174  | 0.441            | 50 | 0.043           | 71 | 0.968            | 175  |  |
| 380 | 0.949           | 174  | 0.428            | 49 | 0.044           | 72 | 0.937            | 175  |  |
| 390 | 0.949           | 174  | 0.417            | 49 | 0.045           | 74 | 0.907            | 176  |  |
| 400 | 0.949           | 174  | 0.409            | 47 | 0.044           | 77 | 0.912            | 177  |  |
| 410 | 0.950           | 173  | 0.390            | 46 | 0.046           | 74 | 0.962            | 175  |  |
| 420 | 0.950           | 173  | 0.377            | 45 | 0.047           | 71 | 0.971            | 174  |  |
| 430 | 0.950           | 173  | 0.369            | 45 | 0.050           | 72 | 0.948            | 176  |  |
| 440 | 0.951           | 173  | 0.368            | 47 | 0.052           | 74 | 0.953            | 176  |  |

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Table 1. Common Source S-Parameters (VDS = 12.5 V, ID = 4.5 A) (continued)

| f    | S-              | s <sub>11</sub> |                  | 21 | s <sub>12</sub> |    | s <sub>22</sub>  |     |
|------|-----------------|-----------------|------------------|----|-----------------|----|------------------|-----|
| MHz  | S <sub>11</sub> | ф               | \$ <sub>21</sub> | ф  | S <sub>12</sub> | ф  | \$ <sub>22</sub> | ф   |
| 450  | 0.951           | 172             | 0.371            | 42 | 0.053           | 76 | 0.943            | 175 |
| 460  | 0.952           | 172             | 0.347            | 44 | 0.053           | 72 | 0.965            | 172 |
| 470  | 0.952           | 172             | 0.331            | 43 | 0.053           | 71 | 0.933            | 173 |
| 480  | 0.953           | 172             | 0.323            | 43 | 0.056           | 71 | 0.936            | 173 |
| 490  | 0.953           | 171             | 0.317            | 41 | 0.059           | 72 | 0.965            | 173 |
| 500  | 0.954           | 171             | 0.306            | 41 | 0.061           | 74 | 0.963            | 173 |
| 600  | 0.957           | 168             | 0.267            | 35 | 0.069           | 77 | 0.941            | 171 |
| 700  | 0.965           | 165             | 0.224            | 35 | 0.090           | 70 | 0.958            | 169 |
| 800  | 0.967           | 160             | 0.219            | 32 | 0.099           | 67 | 0.937            | 164 |
| 900  | 0.980           | 156             | 0.214            | 33 | 0.114           | 69 | 0.943            | 164 |
| 1000 | 0.986           | 151             | 0.218            | 34 | 0.146           | 67 | 0.955            | 162 |

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#### Table 2. Common Source S-Parameters (VDS = 24 V, ID = 4.5 A)

| f   | S <sub>11</sub> |      | S                | 21 | S.              | 12 | S               | 22   |
|-----|-----------------|------|------------------|----|-----------------|----|-----------------|------|
| MHz | S <sub>11</sub> | ф    | \$ <sub>21</sub> | ф  | S <sub>12</sub> | ф  | S <sub>22</sub> | ф    |
| 30  | 0.914           | -174 | 9.08             | 87 | 0.011           | 19 | 0.882           | -178 |
| 40  | 0.918           | -176 | 6.29             | 86 | 0.011           | 22 | 0.876           | -176 |
| 50  | 0.918           | -177 | 5.31             | 82 | 0.011           | 26 | 0.871           | 180  |
| 60  | 0.917           | -177 | 4.35             | 82 | 0.012           | 29 | 0.871           | -179 |
| 70  | 0.919           | -178 | 3.70             | 79 | 0.012           | 32 | 0.865           | -179 |
| 80  | 0.919           | -178 | 3.16             | 77 | 0.013           | 37 | 0.857           | -179 |
| 90  | 0.920           | -179 | 2.81             | 75 | 0.013           | 42 | 0.851           | -180 |
| 100 | 0.921           | -179 | 2.55             | 74 | 0.014           | 46 | 0.863           | -179 |
| 110 | 0.922           | -179 | 2.27             | 73 | 0.014           | 47 | 0.876           | -178 |
| 120 | 0.923           | -179 | 2.08             | 70 | 0.015           | 49 | 0.867           | -179 |
| 130 | 0.923           | -180 | 1.92             | 70 | 0.016           | 51 | 0.880           | -178 |
| 140 | 0.924           | -180 | 1.78             | 67 | 0.017           | 55 | 0.880           | -179 |
| 150 | 0.925           | -180 | 1.68             | 65 | 0.018           | 58 | 0.904           | 179  |
| 160 | 0.926           | 180  | 1.53             | 64 | 0.018           | 60 | 0.901           | -180 |
| 170 | 0.927           | 180  | 1.42             | 62 | 0.018           | 61 | 0.900           | -179 |
| 180 | 0.928           | 180  | 1.34             | 62 | 0.020           | 61 | 0.901           | -179 |
| 190 | 0.929           | 179  | 1.28             | 60 | 0.021           | 63 | 0.906           | -179 |
| 200 | 0.930           | 179  | 1.19             | 58 | 0.022           | 65 | 0.892           | 179  |
| 210 | 0.931           | 179  | 1.12             | 56 | 0.022           | 67 | 0.902           | 178  |
| 220 | 0.932           | 179  | 1.06             | 55 | 0.023           | 68 | 0.903           | 179  |
| 230 | 0.933           | 179  | 0.988            | 53 | 0.024           | 67 | 0.931           | 179  |
| 240 | 0.934           | 178  | 0.960            | 53 | 0.025           | 69 | 0.889           | 179  |
| 250 | 0.934           | 178  | 0.910            | 52 | 0.026           | 73 | 0.877           | 180  |
| 260 | 0.935           | 178  | 0.866            | 50 | 0.026           | 74 | 0.895           | 180  |
| 270 | 0.936           | 178  | 0.838            | 49 | 0.027           | 74 | 0.908           | 180  |
| 280 | 0.937           | 177  | 0.803            | 49 | 0.029           | 71 | 0.923           | 179  |
| 290 | 0.939           | 177  | 0.766            | 46 | 0.030           | 72 | 0.915           | 177  |

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Table 2. Common Source S-Parameters (VDS = 24 V, ID = 4.5 A) (continued)

| f    | S               | 11  | S                | 21 | S.              | 12 | S                | 22   |
|------|-----------------|-----|------------------|----|-----------------|----|------------------|------|
| MHz  | S <sub>11</sub> | ф   | \$ <sub>21</sub> | ф  | S <sub>12</sub> | ф  | \$ <sub>22</sub> | ф    |
| 300  | 0.939           | 177 | 0.744            | 46 | 0.032           | 76 | 0.907            | 178  |
| 310  | 0.939           | 177 | 0.702            | 46 | 0.032           | 81 | 0.908            | 180  |
| 320  | 0.940           | 176 | 0.660            | 45 | 0.031           | 81 | 0.913            | 178  |
| 330  | 0.941           | 176 | 0.623            | 41 | 0.031           | 75 | 0.909            | 177  |
| 340  | 0.942           | 176 | 0.613            | 42 | 0.035           | 71 | 0.910            | 178  |
| 350  | 0.943           | 176 | 0.599            | 41 | 0.039           | 78 | 0.905            | -180 |
| 360  | 0.943           | 175 | 0.585            | 41 | 0.040           | 83 | 0.913            | 179  |
| 370  | 0.943           | 175 | 0.556            | 39 | 0.037           | 85 | 0.924            | 176  |
| 380  | 0.944           | 175 | 0.534            | 38 | 0.035           | 80 | 0.922            | 175  |
| 390  | 0.944           | 175 | 0.512            | 38 | 0.037           | 73 | 0.907            | 176  |
| 400  | 0.946           | 174 | 0.503            | 37 | 0.043           | 76 | 0.906            | 179  |
| 410  | 0.948           | 174 | 0.482            | 36 | 0.049           | 81 | 0.944            | 177  |
| 420  | 0.948           | 174 | 0.464            | 35 | 0.047           | 87 | 0.940            | 176  |
| 430  | 0.947           | 174 | 0.450            | 36 | 0.040           | 88 | 0.912            | 176  |
| 440  | 0.947           | 173 | 0.440            | 36 | 0.039           | 79 | 0.947            | 176  |
| 450  | 0.948           | 173 | 0.445            | 32 | 0.047           | 73 | 0.944            | 177  |
| 460  | 0.951           | 173 | 0.414            | 32 | 0.057           | 75 | 0.959            | 174  |
| 470  | 0.952           | 173 | 0.397            | 32 | 0.057           | 86 | 0.913            | 176  |
| 480  | 0.951           | 172 | 0.387            | 33 | 0.050           | 95 | 0.908            | 175  |
| 490  | 0.950           | 172 | 0.376            | 31 | 0.042           | 90 | 0.941            | 174  |
| 500  | 0.950           | 172 | 0.361            | 31 | 0.044           | 74 | 0.963            | 175  |
| 600  | 0.957           | 168 | 0.287            | 24 | 0.073           | 75 | 0.932            | 172  |
| 700  | 0.965           | 164 | 0.231            | 24 | 0.091           | 70 | 0.952            | 169  |
| 800  | 0.966           | 160 | 0.216            | 23 | 0.091           | 67 | 0.928            | 163  |
| 900  | 0.979           | 156 | 0.205            | 27 | 0.112           | 69 | 0.930            | 164  |
| 1000 | 0.981           | 150 | 0.206            | 29 | 0.146           | 58 | 0.947            | 162  |

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The RF MOSFET Line 100W, 500MHz, 28V

Table 3. Common Source S-Parameters ( $V_{DS}$  = 28 V,  $I_{D}$  = 4.5 A)

| f   | s               | 11   | S                | 21 | S.              | 12 | S                | s <sub>22</sub> |  |
|-----|-----------------|------|------------------|----|-----------------|----|------------------|-----------------|--|
| MHz | S <sub>11</sub> | ф    | \$ <sub>21</sub> | ф  | S <sub>12</sub> | ф  | \$ <sub>22</sub> | ф               |  |
| 30  | 0.910           | -173 | 9.76             | 87 | 0.011           | 17 | 0.872            | -177            |  |
| 40  | 0.913           | -175 | 6.73             | 86 | 0.011           | 17 | 0.860            | -174            |  |
| 50  | 0.913           | -176 | 5.69             | 81 | 0.011           | 21 | 0.849            | -179            |  |
| 60  | 0.913           | -177 | 4.66             | 81 | 0.012           | 26 | 0.846            | -178            |  |
| 70  | 0.915           | -177 | 3.97             | 78 | 0.012           | 31 | 0.853            | -179            |  |
| 80  | 0.916           | -178 | 3.39             | 76 | 0.012           | 33 | 0.858            | -178            |  |
| 90  | 0.916           | -178 | 3.01             | 74 | 0.012           | 34 | 0.853            | -178            |  |
| 100 | 0.917           | -178 | 2.73             | 73 | 0.013           | 36 | 0.851            | -177            |  |
| 110 | 0.918           | -179 | 2.42             | 72 | 0.014           | 41 | 0.849            | -177            |  |
| 120 | 0.919           | -179 | 2.22             | 68 | 0.014           | 48 | 0.853            | -178            |  |
| 130 | 0.920           | -179 | 2.05             | 68 | 0.014           | 52 | 0.879            | -178            |  |
| 140 | 0.921           | -179 | 1.90             | 66 | 0.014           | 52 | 0.894            | -178            |  |
| 150 | 0.922           | -180 | 1.79             | 64 | 0.015           | 51 | 0.898            | -178            |  |

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The RF MOSFET Line 100W, 500MHz, 28V

Table 3. Common Source S-Parameters (VDS = 28 V, ID = 4.5 A) (continued)

| f    | s               | 11   | S                | 21 | S               | 12 | S                | 22   |
|------|-----------------|------|------------------|----|-----------------|----|------------------|------|
| MHz  | S <sub>11</sub> | ф    | \$ <sub>21</sub> | ф  | S <sub>12</sub> | ф  | \$ <sub>22</sub> | ф    |
| 160  | 0.923           | -180 | 1.63             | 63 | 0.016           | 53 | 0.880            | -177 |
| 170  | 0.924           | -180 | 1.50             | 61 | 0.017           | 58 | 0.890            | -178 |
| 180  | 0.925           | 180  | 1.42             | 60 | 0.019           | 62 | 0.904            | -178 |
| 190  | 0.926           | 180  | 1.35             | 58 | 0.019           | 64 | 0.922            | -179 |
| 200  | 0.928           | 179  | 1.26             | 56 | 0.019           | 63 | 0.914            | -179 |
| 210  | 0.929           | 179  | 1.19             | 54 | 0.020           | 62 | 0.897            | -179 |
| 220  | 0.930           | 179  | 1.12             | 53 | 0.022           | 64 | 0.881            | -179 |
| 230  | 0.932           | 179  | 1.04             | 51 | 0.024           | 67 | 0.907            | 180  |
| 240  | 0.932           | 179  | 1.01             | 51 | 0.024           | 69 | 0.892            | 179  |
| 250  | 0.933           | 178  | 0.955            | 49 | 0.024           | 70 | 0.910            | -180 |
| 260  | 0.934           | 178  | 0.912            | 47 | 0.025           | 70 | 0.912            | -178 |
| 270  | 0.936           | 178  | 0.882            | 46 | 0.027           | 71 | 0.904            | -178 |
| 280  | 0.936           | 178  | 0.842            | 46 | 0.029           | 72 | 0.901            | -180 |
| 290  | 0.938           | 177  | 0.798            | 43 | 0.028           | 71 | 0.920            | 177  |
| 300  | 0.939           | 177  | 0.770            | 44 | 0.030           | 71 | 0.930            | 178  |
| 310  | 0.939           | 177  | 0.731            | 43 | 0.032           | 72 | 0.934            | -179 |
| 320  | 0.941           | 177  | 0.690            | 42 | 0.035           | 74 | 0.939            | -180 |
| 330  | 0.942           | 176  | 0.655            | 39 | 0.036           | 76 | 0.895            | 180  |
| 340  | 0.942           | 176  | 0.639            | 40 | 0.035           | 75 | 0.892            | 179  |
| 350  | 0.942           | 176  | 0.613            | 39 | 0.036           | 75 | 0.906            | -180 |
| 360  | 0.943           | 175  | 0.601            | 38 | 0.040           | 71 | 0.945            | 179  |
| 370  | 0.945           | 175  | 0.577            | 36 | 0.045           | 71 | 0.960            | 178  |
| 380  | 0.946           | 175  | 0.555            | 35 | 0.047           | 74 | 0.928            | 178  |
| 390  | 0.947           | 175  | 0.531            | 35 | 0.045           | 79 | 0.893            | 178  |
| 400  | 0.946           | 174  | 0.518            | 34 | 0.042           | 80 | 0.892            | 179  |
| 410  | 0.947           | 174  | 0.492            | 33 | 0.044           | 72 | 0.948            | 176  |
| 420  | 0.948           | 174  | 0.472            | 32 | 0.049           | 67 | 0.960            | 176  |
| 430  | 0.950           | 173  | 0.462            | 32 | 0.056           | 71 | 0.936            | 179  |
| 440  | 0.951           | 173  | 0.455            | 32 | 0.058           | 78 | 0.945            | 179  |
| 450  | 0.951           | 173  | 0.460            | 30 | 0.054           | 82 | 0.920            | 177  |
| 460  | 0.950           | 173  | 0.424            | 30 | 0.050           | 73 | 0.951            | 173  |
| 470  | 0.950           | 172  | 0.400            | 29 | 0.053           | 65 | 0.937            | 174  |
| 480  | 0.952           | 172  | 0.389            | 29 | 0.063           | 65 | 0.941            | 175  |
| 490  | 0.954           | 172  | 0.382            | 27 | 0.071           | 72 | 0.960            | 175  |
| 500  | 0.955           | 172  | 0.367            | 27 | 0.069           | 80 | 0.954            | 176  |
| 600  | 0.958           | 168  | 0.284            | 22 | 0.071           | 80 | 0.935            | 172  |
| 700  | 0.967           | 164  | 0.226            | 22 | 0.088           | 71 | 0.950            | 169  |
| 800  | 0.967           | 160  | 0.211            | 22 | 0.096           | 67 | 0.929            | 164  |
| 900  | 0.979           | 156  | 0.197            | 26 | 0.116           | 69 | 0.929            | 165  |
| 1000 | 0.978           | 150  | 0.200            | 29 | 0.139           | 67 | 0.944            | 163  |

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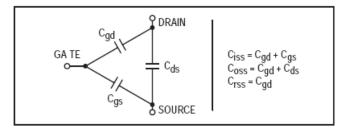
#### RF POWER MOSFET CONSIDERATIONS

#### **MOSFET CAPACITANCES**

The physical structure of a MOSFET results in capacitors between the terminals. The metal oxide gate structure determines the capacitors from gate—to—drain (Cgd), and gate—to—source (Cgs). The PN junction formed during the fabrication of the MOSFET results in a junction capacitance from drain—to—source (Cds).

These capacitances are characterized as input (Ciss), output (Coss) and reverse transfer (Crss) capacitances on datasheets. The relationships between the interterminal capacitances and those given on data sheets are shown below. The Ciss can be specified in two ways:

- Drain shorted to source and positive voltage at the gate.
- Positive voltage of the drain in respect to source and zero volts at the gate. In the latter case the numbers are lower. However, neither method represents the actual operating conditions in RF applications.



#### **DRAIN CHARACTERISTICS**

One figure of merit for a FET is its static resistance in the full—on condition. This on—resistance, VDS(on), occurs in the linear region of the output characteristic and is specified under specific test conditions for gate—source voltage and drain current. For MOSFETs, VDS(on) has a positive temperature coefficient and constitutes an important design consideration at high temperatures, because it contributes to the power dissipation within the device.

#### **GATE CHARACTERISTICS**

Commitment to produce in volume is not guaranteed.

The gate of the MOSFET is a polysilicon material, and is electrically isolated from the source by a layer of oxide. The input resistance is very high — on the order of 109 ohms — resulting in a leakage current of a few nanoamperes. Gate control is achieved by applying a positive voltage slightly in excess of the gate—to—source threshold voltage, VGS(th).

**Gate Voltage Rating** — Never exceed the gate voltage rating (or any of the maximum ratings on the front page). Exceeding the rated VGS can result in permanent damage to the oxide layer in the gate region.

**Gate Termination** — The gates of this device are essentially capacitors. Circuits that leave the gate open-circuited or floating should be avoided. These conditions can result in turn-on of the devices due to voltage build-up on the input capacitor due to leakage currents or pickup.

Gate Protection — These devices do not have an internalmonolithic zener diode from gate—to—source. If gate protection is required, an external zener diode is recommended. Using a resistor to keep the gate—to—source impedance low also helps damp transients and serves another important function. Voltage transients on the drain can be coupled to the gate through the parasitic gate—drain capacitance. If the gate—to—source impedance and the rate of voltage change on the drain are both high, then the signal coupled to the gate may be large enough to exceed the gate—threshold voltage and turn the device on.

#### HANDLING CONSIDERATIONS

When shipping, the devices should be transported only in antistatic bags or conductive foam. Upon removal from the packaging, careful handling procedures should be adhered to. Those handling the devices should wear grounding straps and devices not in the antistatic packaging should be kept in metal tote bins. MOSFETs should be handled by the case and not by the leads, and when testing the device, all leads should make good electrical contact before voltage is applied. As a final note, when placing the FET into the system it is designed for, soldering should be done with grounded equipment.

#### **DESIGN CONSIDERATIONS**

The MRF275L is a RF power N-channel enhancement mode field-effect transistor (FETs) designed for HF, VHF and UHF power amplifier applications. M/A-COM RF MOSFETs feature a vertical structure with a planar design. M/A-COM Application Note AN211A, FETs in Theory and Practice, is suggested reading for those not familiar with the construction and characteristics of FETs. The major advantages of RF power FETs include high gain, low noise, simple bias systems, relative immunity from thermal runaway, and the ability to withstand severely mismatched loads without suffering damage. Power output can be varied over a wide range with a low power dc control signal.

#### DC BIAS

The MRF275L is an enhancement mode FET and, therefore, does not conduct when drain voltage is applied. Drain current flows when a positive voltage is applied to the gate. RF power FETs require forward bias for

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## The RF MOSFET Line 100W, 500MHz, 28V

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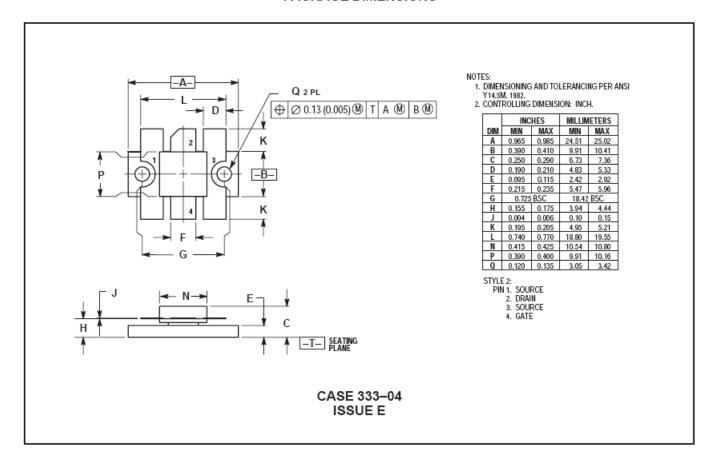
optimum performance. The value of quiescent drain current (IDQ) is not critical for many applications. The MRF275L was characterized at IDQ = 100 mA, each side, which is the suggested minimum value of IDQ. For special applications such as linear amplification, IDQ may have to be selected to optimize the critical parameters. The gate is a dc open circuit and draws no current. Therefore, the gate bias circuit may be just a simple resistive divider network. Some applications

may require a more elaborate bias system.

#### **GAIN CONTROL**

Power output of the MRF275L may be controlled from its rated value down to zero (negative gain) by varying the dc gate voltage. This feature facilitates the design of manual gain control, AGC/ALC and modulation systems.

#### PACKAGE DIMENSIONS



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